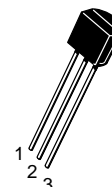
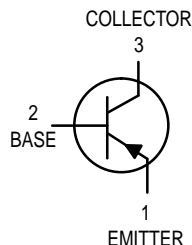


General Purpose Transistors

PNP Silicon

2N4402
2N4403*

*Motorola Preferred Device



CASE 29-04, STYLE 1
TO-92 (TO-226AA)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	40	Vdc
Collector–Base Voltage	V_{CBO}	40	Vdc
Emitter–Base Voltage	V_{EBO}	5.0	Vdc
Collector Current — Continuous	I_C	600	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12	Watt mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ⁽¹⁾ ($I_C = 1.0 \text{ mAdc}, I_E = 0$)	$V_{(BR)CEO}$	40	—	Vdc
Collector–Base Breakdown Voltage ($I_C = 0.1 \text{ mAdc}, I_E = 0$)	$V_{(BR)CBO}$	40	—	Vdc
Emitter–Base Breakdown Voltage ($I_E = 0.1 \text{ mAdc}, I_C = 0$)	$V_{(BR)EBO}$	5.0	—	Vdc
Base Cutoff Current ($V_{CE} = 35 \text{ Vdc}, V_{EB} = 0.4 \text{ Vdc}$)	I_{BEV}	—	0.1	μAdc
Collector Cutoff Current ($V_{CE} = 35 \text{ Vdc}, V_{EB} = 0.4 \text{ Vdc}$)	I_{CEX}	—	0.1	μAdc

1. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

Preferred devices are Motorola recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain ($I_C = 0.1 \text{ mA dc}, V_{CE} = 1.0 \text{ V dc}$)	h_{FE}	30	—	—
($I_C = 1.0 \text{ mA dc}, V_{CE} = 1.0 \text{ V dc}$)		30	—	
		60	—	
($I_C = 10 \text{ mA dc}, V_{CE} = 1.0 \text{ V dc}$)		50	—	
		100	—	
($I_C = 150 \text{ mA dc}, V_{CE} = 2.0 \text{ V dc}$) ⁽¹⁾		50	150	
		100	300	
($I_C = 500 \text{ mA dc}, V_{CE} = 2.0 \text{ V dc}$) ⁽¹⁾	Both	20	—	
Collector–Emitter Saturation Voltage ⁽¹⁾ ($I_C = 150 \text{ mA dc}, I_B = 15 \text{ mA dc}$) ($I_C = 500 \text{ mA dc}, I_B = 50 \text{ mA dc}$)	$V_{CE(sat)}$	—	0.4 0.75	Vdc
Base–Emitter Saturation Voltage ⁽¹⁾ ($I_C = 150 \text{ mA dc}, I_B = 15 \text{ mA dc}$) ($I_C = 500 \text{ mA dc}, I_B = 50 \text{ mA dc}$)	$V_{BE(sat)}$	0.75 —	0.95 1.3	Vdc

SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_C = 20 \text{ mA dc}, V_{CE} = 10 \text{ V dc}, f = 100 \text{ MHz}$)	f_T	150 200	— —	MHz
Collector–Base Capacitance ($V_{CB} = 10 \text{ V dc}, I_E = 0, f = 1.0 \text{ MHz}$)	C_{cb}	—	8.5	pF
Emitter–Base Capacitance ($V_{EB} = 0.5 \text{ V dc}, I_C = 0, f = 1.0 \text{ MHz}$)	C_{eb}	—	30	pF
Input Impedance ($I_C = 1.0 \text{ mA dc}, V_{CE} = 10 \text{ V dc}, f = 1.0 \text{ kHz}$)	h_{ie}	750 1.5 k	7.5 k 15 k	ohms
Voltage Feedback Ratio ($I_C = 1.0 \text{ mA dc}, V_{CE} = 10 \text{ V dc}, f = 1.0 \text{ kHz}$)	h_{re}	0.1	8.0	$\times 10^{-4}$
Small–Signal Current Gain ($I_C = 1.0 \text{ mA dc}, V_{CE} = 10 \text{ V dc}, f = 1.0 \text{ kHz}$)	h_{fe}	30 60	250 500	—
Output Admittance ($I_C = 1.0 \text{ mA dc}, V_{CE} = 10 \text{ V dc}, f = 1.0 \text{ kHz}$)	h_{oe}	1.0	100	μmhos

SWITCHING CHARACTERISTICS

Delay Time	$(V_{CC} = 30 \text{ V dc}, V_{BE} = +2.0 \text{ V dc}, I_C = 150 \text{ mA dc}, I_{B1} = 15 \text{ mA dc})$	t_d	—	15	ns
Rise Time		t_r	—	20	ns
Storage Time	$(V_{CC} = 30 \text{ V dc}, I_C = 150 \text{ mA dc}, I_{B1} = 15 \text{ mA}, I_{B2} = 15 \text{ mA})$	t_s	—	225	ns
Fall Time		t_f	—	30	ns

1. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

SWITCHING TIME EQUIVALENT TEST CIRCUIT

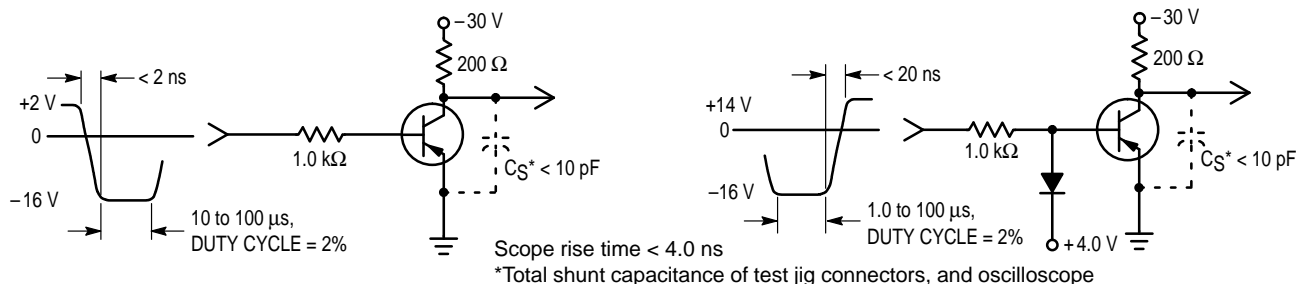


Figure 1. Turn–On Time

Figure 2. Turn–Off Time

TRANSIENT CHARACTERISTICS

— 25°C - - - 100°C

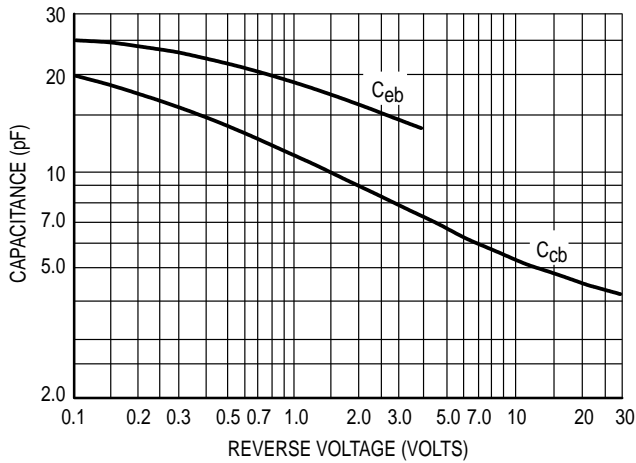


Figure 3. Capacitances

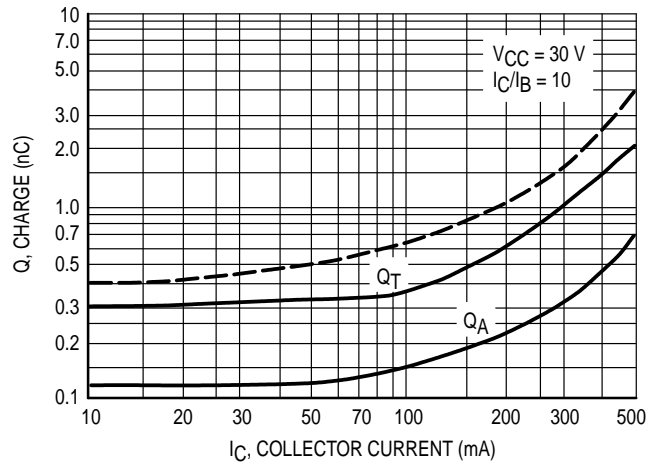


Figure 4. Charge Data

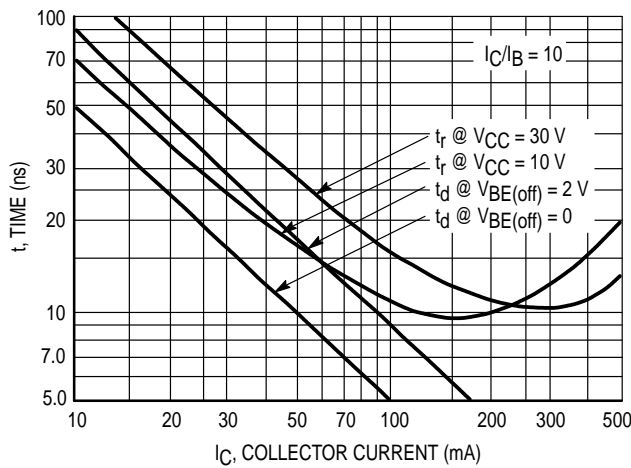


Figure 5. Turn-On Time

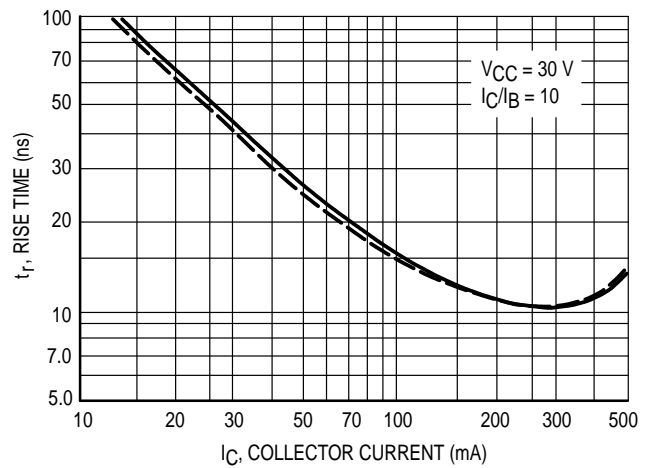


Figure 6. Rise Time

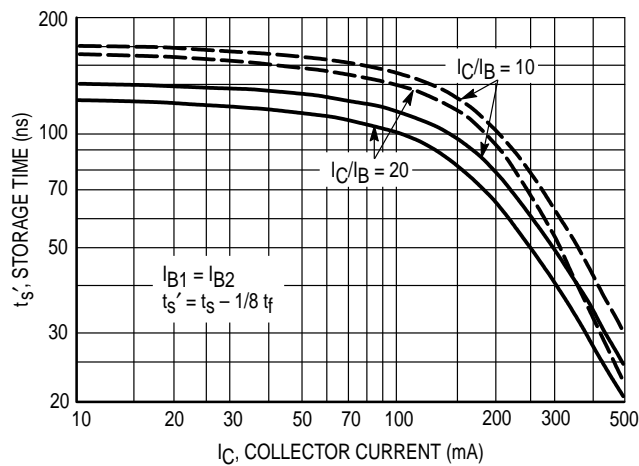


Figure 7. Storage Time

SMALL-SIGNAL CHARACTERISTICS

NOISE FIGURE

$V_{CE} = -10 \text{ Vdc}$, $T_A = 25^\circ\text{C}$

Bandwidth = 1.0 Hz

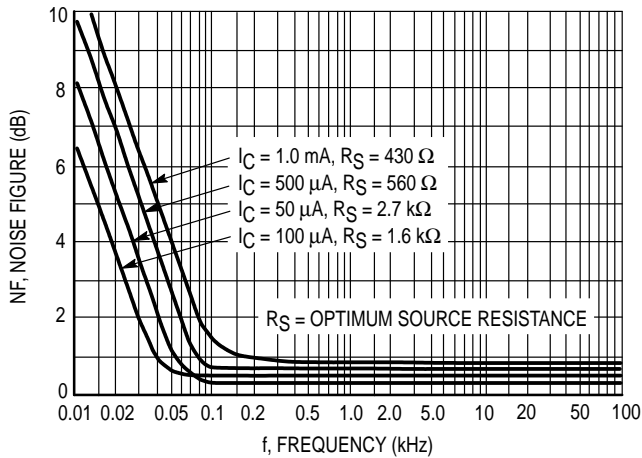


Figure 8. Frequency Effects

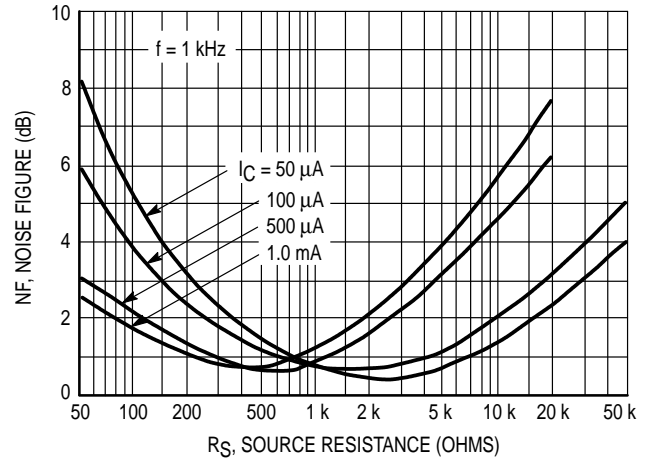


Figure 9. Source Resistance Effects

h PARAMETERS

$V_{CE} = -10 \text{ Vdc}$, $f = 1.0 \text{ kHz}$, $T_A = 25^\circ\text{C}$

This group of graphs illustrates the relationship between h_{fe} and other "h" parameters for this series of transistors. To obtain these curves, a high-gain and a low-gain unit were

selected from both the 2N4402 and 2N4403 lines, and the same units were used to develop the correspondingly-numbered curves on each graph.

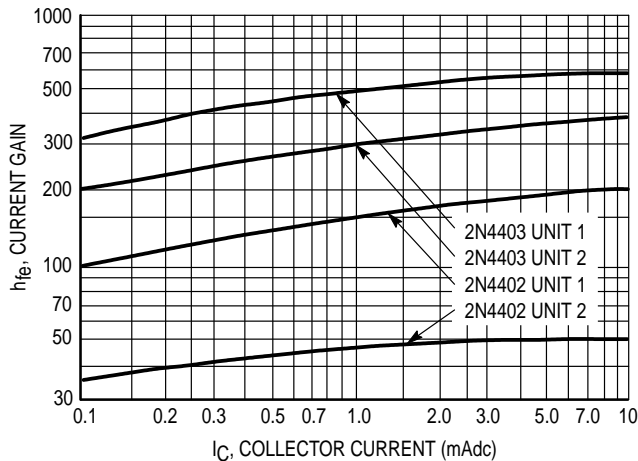


Figure 10. Current Gain

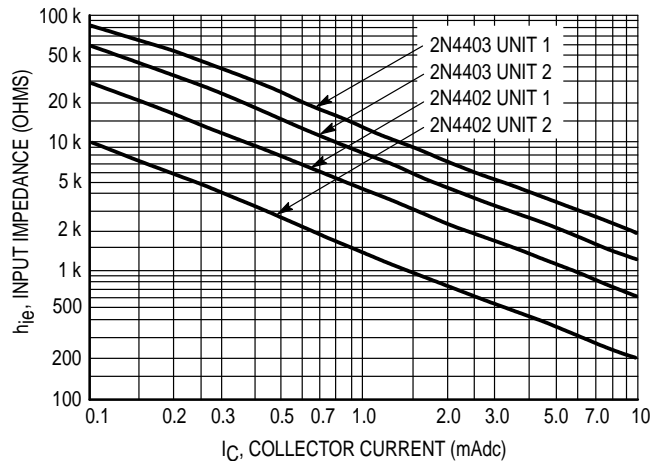


Figure 11. Input Impedance

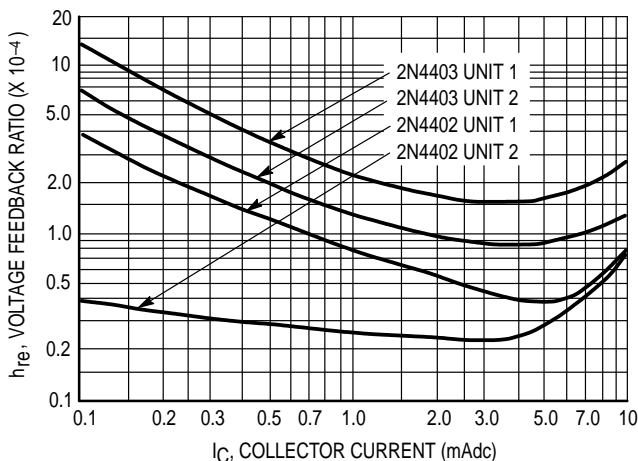


Figure 12. Voltage Feedback Ratio

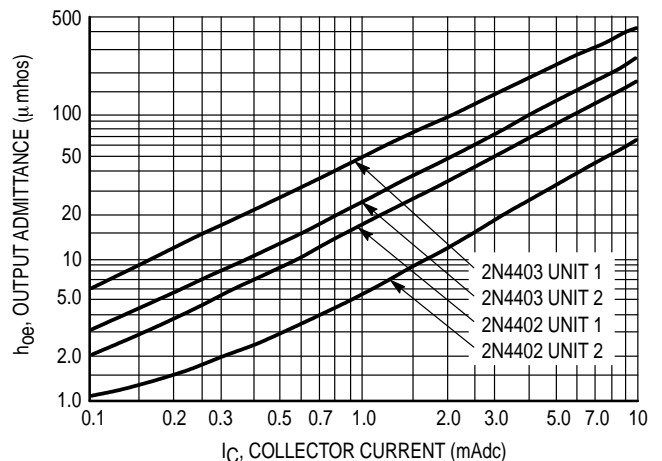


Figure 13. Output Admittance

STATIC CHARACTERISTICS

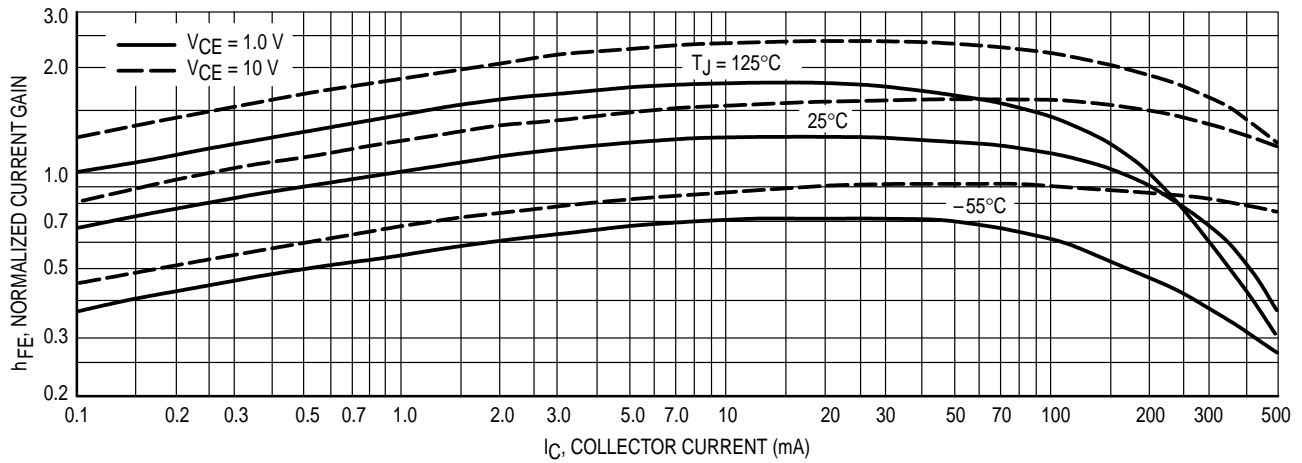


Figure 14. DC Current Gain

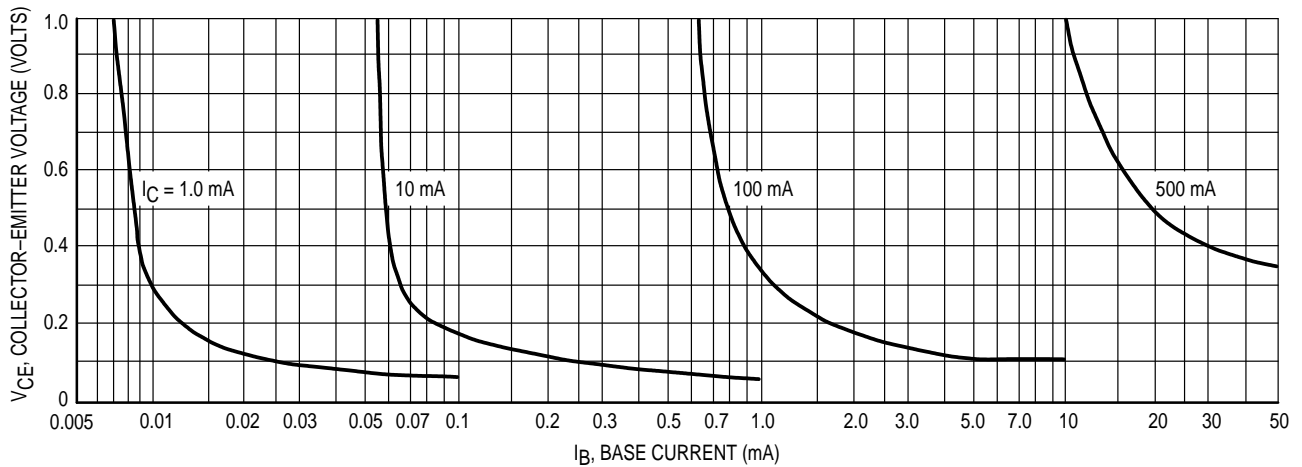


Figure 15. Collector Saturation Region

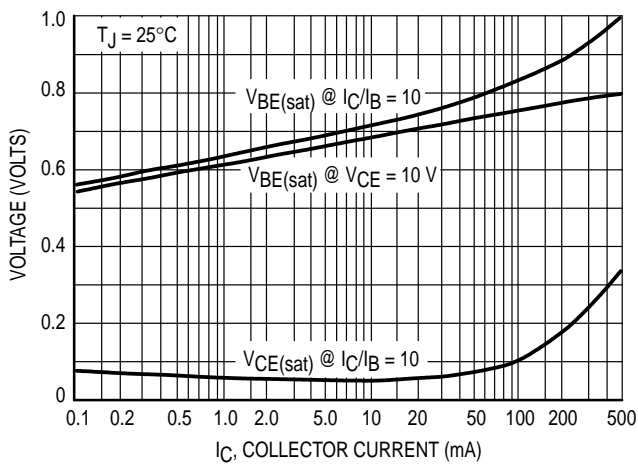


Figure 16. "On" Voltages

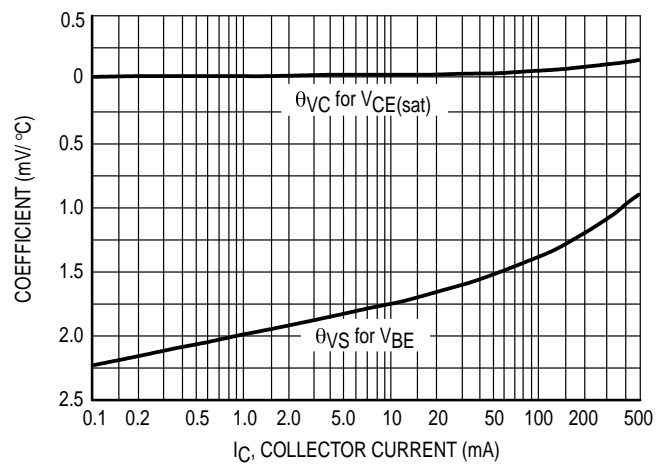


Figure 17. Temperature Coefficients

PACKAGE DIMENSIONS



**CASE 029-04
(TO-226AA)
ISSUE AD**

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K. MINIMUM LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

STYLE 1:

- PIN 1. EMITTER
2. BASE
3. COLLECTOR

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